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## Density functional theory for a model quantum dot: Beyond the local-density approximation

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We study both static and transport properties of model quantum dots, employing density functional theory as well as (numerically) exact methods. For the lattice model under consideration the accuracy of the local-density approximation generally is poor. For weak interaction, however, accurate results are achieved within the optimized effective potential method, while for intermediate interaction strengths a method combining the exact diagonalization of small clusters with density functional theory is very successful. Results obtained from the latter approach yield very good agreement with density matrix renormalization group studies, where the full Hamiltonian consisting of the dot and the attached leads has to be diagonalized. Furthermore we address the question of whether static density functional theory is able to predict the exact linear conductance through the dot correctly—with, in general, a negative answer.

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#### I. INTRODUCTION

Density functional theory (DFT) is an efficient tool for determining the electronic structure of solids. While originally developed for continuum systems with Coulomb interaction, <sup>1,2</sup> DFT has also been applied to lattice models, such as the Hubbard model or models of spinless fermions. <sup>3–6</sup> These lattice models often allow for exact solutions—either analytically or based on numerics—which hence can serve as benchmarks for assessing the quality of approximations.

Very popular in solid-state applications is the local-density approximation (LDA) where the exchange-correlation energy of the inhomogeneous system under consideration is constructed via a local approximation from the homogeneous electron system. Recently a lattice version of the LDA has been suggested for one-dimensional systems, where the underlying homogeneous system can be solved using the Bethe ansatz. For example, it has been demonstrated that the Bethe ansatz LDA describes well the low-frequency, long-wavelength excitations of the interacting one-dimensional system, i.e., of a Luttinger liquid. 8,9

On the other hand the LDA often fails in correlated systems and systematic improvements beyond the LDA are difficult. In this article we focus on a model of spinless fermions describing interacting electrons on a quantum dot. In the first step we compare the equilibrium properties of the system, i.e., the number of particles on the dot as a function of the gate voltage obtained within different approximations for the exchange-correlation energy: the LDA and the optimized effective potential (OEP) approach. Furthermore we suggest a novel method where the exchange-correlation energy is obtained via the exact diagonalization of a small cluster that is composed of the strongly interacting region and a few additional sites. The accuracy of this novel approach turns out to be by far better than that of the LDA and the OEP.

In the second step we compute the linear conductance through the dot. A general motivation for this study is recent progress in the field of molecular electronics, where DFT-based calculations are a standard tool to calculate electrical conductances. However the conceptional limitations of the approach are not very well understood yet. More specifically we were motivated by the model studies in Refs. 13

and 14. Mera *et al.*<sup>14</sup> stressed that static DFT reproduces the conductance of an interacting system correctly if there exists a Friedel sum rule that relates the conductance with the equilibrium density. Schmitteckert and Evers<sup>13</sup> compared conductances obtained from a density matrix renormalization group calculation with those obtained within static DFT. Close to resonances both conductances were in very good agreement, while off-resonance there was a considerable discrepancy. This discrepancy is due to a difference between the voltage in the Kohn-Sham system and in the physical system,  $^{12,15}$   $U_{\rm KS} - U = U^{\rm xc}$ . One of the questions we address is whether  $U^{\rm xc}$  depends on the distance between the interacting region and the reservoirs.

In the following section we introduce the model under investigation. In Sec. III, devoted to static DFT, we discuss the approximations used to obtain the exchange-correlation energy. Section IV is devoted to transport: We rederive the Meir-Wingreen formula for the conductance starting from the dynamical density-density response function, and we apply the formula to calculate the conductance for our model. The final section contains a summary as well as our conclusions.

#### II. THE MODEL

We study a model where a chain of *N* lattice sites is coupled to two reservoirs

$$\hat{H} = \hat{H}_L + \hat{H}_{LC} + \hat{H}_C + \hat{H}_{CR} + \hat{H}_R. \tag{1}$$

The Hamiltonian of the chain reads

$$\hat{H}_{C} = -\sum_{l=1}^{N-1} t_{l,l+1} (\hat{c}_{l}^{\dagger} \hat{c}_{l+1} + \hat{c}_{l+1}^{\dagger} \hat{c}_{l}) + \sum_{l=1}^{N} v_{l} \hat{n}_{l} + \sum_{l=1}^{N-1} V_{l,l+1} \left( \hat{n}_{l} - \frac{1}{2} \right) \left( \hat{n}_{l+1} - \frac{1}{2} \right),$$
 (2)

where  $\hat{c}_l^+$  and  $\hat{c}_l$  are fermion creation and annihilation operators,  $\hat{n}_l = \hat{c}_l^+ \hat{c}_l$  counts the fermions on lattice site l. The hopping matrix elements  $t_{l,l+1}$  are chosen such that the system

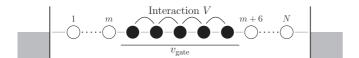


FIG. 1. Schematic view of the model under consideration: A quantum dot (solid circles) attached to left and right leads, each of them consisting of m noninteracting sites (open circles) and a reservoir described by a continuum of states (shaded regions). The electrons on the dot (sites m+1 to m+5) interact and their potential energy can be tuned by a gate voltage.

resembles a quantum dot that is weakly coupled to left and right leads, cf. Fig. 1, and are explicitly given by

$$t_{l,l+1} = \begin{cases} t & l = 1, \dots, m-1, m+6, \dots, N-1, \\ t' & l = m \text{ and } l = m+5, \\ t_{\text{dot}} & l = m+1, \dots, m+4. \end{cases}$$
 (3)

In the following we choose t'=0.2t and  $t_{\rm dot}=0.5t$ . The interaction strength and the potentials are constant within the quantum dot,  $V_{l,l+1}=V$  and  $v_l=v_{\rm gate}$ , and zero outside. The reservoirs, chosen to be noninteracting fermions, are described by

$$\hat{H}_{L/R} = \sum_{k} \epsilon_k \hat{c}_{kL/R}^{\dagger} \hat{c}_{kL/R}, \tag{4}$$

and finally the coupling between the chain and the left reservoir reads

$$\hat{H}_{LC} = -\sum_{k} t_k (\hat{c}_{kL}^{\dagger} \hat{c}_1 + \hat{c}_1^{\dagger} \hat{c}_{kL})$$
 (5)

and analogously for  $\hat{H}_{CR}$ . The hopping parameters  $t_k$  are fine-tuned such that an electron at the Fermi energy is not backscattered at the interface between the chain and the reservoirs,  $^{13}$   $t_k = \sqrt{t/\pi N(\epsilon_k)}$ , where  $N(\epsilon_k)$  is the density of states in the reservoirs. Up to this point our model is the same as the model studied by Schmitteckert and Evers. In contrast to Ref. 13, however, we replace the discrete levels in the reservoirs by a continuum of a wide and flat band. The tunneling rate from the chain to the left or right reservoir is then given by

$$\Gamma_{L/R} = 2\pi \sum_{k} |t_k|^2 \delta(\epsilon_F - \epsilon_k)$$
 (6)

$$= 2\pi |t_k|^2 N(\epsilon_k)|_{k=k_E} = 2t.$$
 (7)

Note that in the continuum limit the density of states in the reservoirs goes to infinity, and thus—in order to keep  $\Gamma_{L/R}$  constant—the coupling strength between the states in the reservoirs and the chain has to go to zero.

## III. STATIC DENSITY FUNCTIONAL THEORY

Strictly speaking lattice DFT as presented here is a site occupation function theory; compare Refs. 5 and 16. The theory relies on the fact that there is a one-to-one correspondence between local potentials  $\{v_i\}$  and the ground-state expectation values of the site occupations  $\{n_i\}$ . Therefore it is—in principle—possible to express all quantities that can be obtained from the ground-state wave function as a function

of the densities. The site occupations as a function of the potentials can be found as derivatives of the ground-state energy with respect to the local potential

$$n_i = \frac{\partial E_0}{\partial v_i}. (8)$$

In order to determine the potentials from the densities it is convenient to define the function

$$F(\lbrace n_i \rbrace) = \min_{\Psi \to \lbrace n_i \rbrace} \langle \Psi | \hat{T} + \hat{V} | \Psi \rangle, \tag{9}$$

where  $\Psi \to \{n_i\}$  indicates that the minimization is constrained to such wave functions  $\Psi$  that yield the given site occupations  $\{n_i\}$ . Here  $\hat{T}$  and  $\hat{V}$  are the kinetic and the interaction parts of the Hamiltonian, respectively. The ground-state energy is obtained by minimizing the function

$$E(\{n_i\}) = F(\{n_i\}) + \sum_{i} v_i n_i$$
 (10)

with respect to  $n_i$ . When we minimize E under the constraint of a constant particle number we obtain the potential up to an additive constant (the Lagrange multiplier):

$$v_i = -\frac{\partial F}{\partial n_i} + \lambda. \tag{11}$$

A major step toward the practical implementation of DFT is to employ a noninteracting auxiliary Hamiltonian  $\hat{H}^s$  (Kohn-Sham Hamiltonian) in order to calculate the density profile,

$$\hat{H}^s = \hat{T} + \sum_i v_i^s \hat{n}_i, \tag{12}$$

where the potentials  $v_i^s$  have to be chosen such that in the ground-state of  $H^s$  the site occupations  $n_i$  are the same as in the interacting model. In analogy to the interacting system, the ground-state energy of the Kohn-Sham system is found by minimizing

$$E^{s}(\{n_{i}\}) = F^{s}(\{n_{i}\}) + \sum_{i} v_{i}^{s} n_{i}.$$
 (13)

Combining Eqs. (10) and (13) yields

$$E(\{n_i\}) = E^s(\{n_i\}) + E^{\text{HXC}}(\{n_i\}) + \sum_i (v_i - v_i^s) n_i, \quad (14)$$

with the Hartree-exchange-correlation energy defined by

$$E^{\text{HXC}}(\{n_i\}) = F(\{n_i\}) - F^s(\{n_i\}). \tag{15}$$

The condition that both E and  $E^s$  are minimal for the same set of site occupations  $n_i$  requires that

$$v_i^s = v_i + \frac{\partial E^{\text{HXC}}}{\partial n_i}.$$
 (16)

Up to this point no approximations have been employed. However, to determine  $E^{\rm HXC}$  at a given density exactly is as demanding as finding the ground-state energy for a given potential. The hope is that there exist good approximations for  $E^{\rm HXC}$  that are accessible with low numerical cost but still allow good estimates for the ground-state energy and density. Here and in the following we compare three different approximations: the LDA, the OEP (so-called exact exchange) approximation, and finally a method based on the exact diagonalization of small clusters. Only the last method—which

is computationally the most expensive one—yields reliable results even in the strong interaction regime and can (in principle) be made as accurate as needed by increasing the cluster size.

#### A. Local-density approximation

In the LDA one writes  $E^{\rm HXC}$  as the sum of the Hartree energy plus an exchange-correlation energy which depends only on the local density,

$$E_{\text{LDA}}^{\text{HXC}}(\{n_i\}) = V \sum_{i} n_i n_{i+1} + \sum_{i} \epsilon_{\text{XC}}(n_i).$$
 (17)

The local exchange-correlation energy  $\epsilon_{\rm XC}(n)$  is determined from the ground-state energy density of a homogeneous system at the same density. For the one-dimensional lattice models this quantity can be calculated using the Bethe ansatz (see Refs. 6 and 8). Note that in the Hamiltonian the interaction strength depends on position, and an ambiguity arises in how to determine the exchange-correlation potential for those sites which interact only with one neighbor. For simplicity we used in our numerical implementation of the LDA the same function  $\epsilon^{\rm xc}(n)$  for all interacting lattice sites, i.e., numbers m+1 to m+5.

#### B. Optimized effective potential

In the OEP approach<sup>17</sup> the Hartree-exchange-correlation energy is

$$E_{\text{OEP}}^{\text{HXC}}(\{n_i\}) = V \sum_{i} n_i n_{i+1} + E^{X}(\{n_i\}),$$
 (18)

with the Fock-like exchange energy

$$E^{X} = -V \sum_{i} \langle \hat{c}_{i}^{+} \hat{c}_{i+1} \rangle \langle \hat{c}_{i+1}^{+} \hat{c}_{i} \rangle.$$
 (19)

We calculate the ground-state expectation values  $\langle \hat{c}_i^{\dagger} \hat{c}_{i+1} \rangle$ , etc., self-consistently using the Green's function technique (see Sec. IV). The Kohn-Sham equations (16) are most conveniently solved by iteration. Starting with an initial guess for the potentials  $v_i^s$  we calculate the corresponding site occupations  $n_i$  and the Hartree-exchange-correlation energy  $E^{\rm HXC}$ . Since in the OEP approach  $E^{\rm HXC}$  depends only implicitly on  $n_i$  we rewrite Eq. (16) using

$$\frac{\partial E^{\rm HXC}}{\partial n_i} = \sum_j \frac{\partial E^{\rm HXC}}{\partial v_j^s} \frac{\partial v_j^s}{\partial n_i},\tag{20}$$

where the derivatives of  $E^{\rm HXC}$  with respect to the  $v_j^s$  are calculated numerically and  $\partial v_j^s/\partial n_i$  is obtained by matrix inversion from  $\partial n_i/\partial v_j^s$ . Finally we obtain a new set of Kohn-Sham potentials  $v_i^s$ . The whole procedure is repeated until convergence, i.e., until the difference between old and new potentials is smaller than some given cutoff.

The fact that we use a continuum of states to describe the reservoirs simplifies the task of solving Eq. (16) considerably. Since the states in the reservoirs are only infinitesimally weakly coupled to the dot, the Hartree-exchange-correlation potential in the reservoirs disappears, such that the number of potentials  $v_i^s$  to be determined self-consistently equals the chain length N.

#### C. Exact diagonalization

In our model Hamiltonian electrons interact only in a spatially confined region. In the noninteracting regions we find numerically [e.g., within the OEP approach, see Fig. 6 below; compare also Ref. 13 for density matrix renormalization group (DMRG) results] only small exchange-correlation potentials. This finding motivated us to use the exchange-correlation energy of a small cluster consisting of the interacting region plus a small number of noninteracting sites as an approximation for the exchange-correlation energy of the system attached to reservoirs:

$$E_{\rm ED}^{\rm HXC}(\{n_i\}) = F_{\rm ED}(\{n_i\}) - F_{\rm ED}^{s}(\{n_i\}),$$
 (21)

where  $F_{\rm ED}(\{n_i\})$  and  $F_{\rm ED}^s(\{n_i\})$  are exact on the small cluster and can be obtained by numerical diagonalization.

In this approach we have to fine-tune the local potentials of three different Hamiltonians such that all three yield the same local densities: (i) a cluster of interacting electrons with potentials  $u_i$ , (ii) a cluster of noninteracting electrons with potentials  $u_i^s$ , and (iii) the Kohn-Sham Hamiltonian of the extended quantum dot attached to reservoirs with  $v_i^s = v_i + v_i^{\rm HXC}$ , where  $v_i^{\rm HXC} = u_i - u_i^s$  on the cluster sites and zero outside. Again, in a practical scheme the fine-tuning procedure is performed by iteration. The task of determining the potentials  $u_i$  that correspond to a given set of site occupations  $n_i$  is nontrivial for an interacting system and limits the cluster size in our approach to approximately 12 to 14 sites.

### D. Results

In the following we focus on the particle number in the interacting region,  $N_{\rm dot}$ , as a function of the gate voltage,  $v_{\rm gate}$ , comparing results for the three aforementioned approaches, LDA, OEP, and ED. The data are obtained for a chain of nine sites, i.e., the five-site quantum dot plus two noninteracting

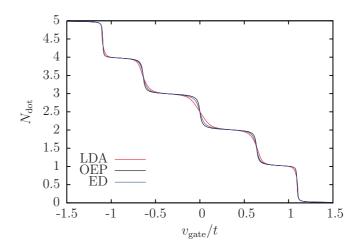


FIG. 2. (Color online) Particle number on the dot,  $N_{\rm dot}$ , as a function of the gate voltage,  $v_{\rm gate}$ , for V/t=0.25 obtained within DFT with three different approximations for the exchange-correlation energy: the local-density approximation (LDA), the optimized effective potential (OEP) approach, and a method based on the exact diagonalization of short chains (ED). Here the chains are nine sites long.

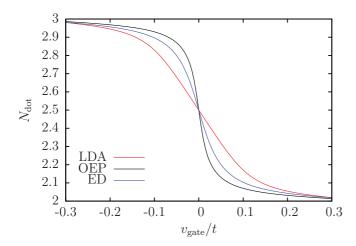


FIG. 3. (Color online)  $N_{\rm dot}$  as a function of  $v_{\rm gate}$  around to the central step for V/t=0.25; for this interaction strength the OEP density is still close to the exact result.

sites on each side of it. Figure 2 shows  $N_{\rm dot}$  for weak interaction strength, V/t=0.25. The three curves nearly coincide with the exception of the regions close to the steps, in particular, around  $v_{\rm gate}=0$ . Here, as pointed out in Fig. 3, the step appears steeper in the OEP approach and flatter in the LDA compared to the ED method.

This trend continues at stronger interaction, V/t = 0.5, where in the OEP approach the particle number even jumps close to  $v_{\rm gate} = 0$  with a small hysteresis region of two stable solutions, while the LDA step flattens out even more, as displayed in Fig. 4. The hysteresis here, as well as in Fig. 5, is an artifact of the method.

In the strong coupling regime (Fig. 5) where V/t = 2, comparison with the exact densities obtained from DMRG calculations<sup>13</sup> shows that the LDA and the OEP approach fail completely. On the other hand, the ED densities agree reasonably well with the exact data. Note, however, that the DMRG data are for a five-site quantum dot with two noninteracting sites attached on the right and three on the left and that the reservoirs are described by a finite set of

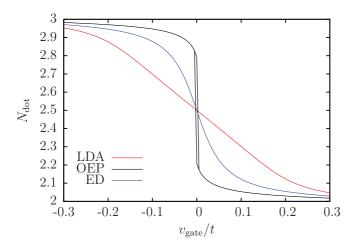
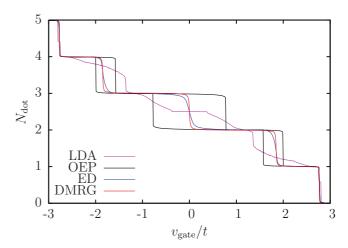


FIG. 4. (Color online)  $N_{\rm dot}$  as a function of  $v_{\rm gate}$  for V/t=0.5. Solving the OEP equations iteratively as a function of gate voltage, two solutions are found close to  $v_{\rm gate}=0$ .



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FIG. 5. (Color online)  $N_{\text{dot}}$  as a function of  $v_{\text{gate}}$  for V/t = 2. For comparison we also include the DMRG results of Ref. 13.

the order of 100 discrete levels instead of a continuum. From the above observations we conclude that in DFT calculations for lattice models LDA and OEP results are reliable in the weak interaction regime. In particular, it can be shown that the OEP density profile is exact to linear order in the interaction strength V. On the other hand, for strongly correlated systems more sophisticated methods like the ED cluster approach are required, even for static properties.

As already mentioned in Sec. III C, far from the interacting region the potential  $v_l^{\rm HXC}$  becomes very small. This is explicitly demonstrated in Fig. 6: In the leads the Hartree-exchange-correlation potential,  $v_l^{\rm HXC}$ , within the OEP approach, is found to be about 3 orders of magnitude smaller than that in the interacting region (see inset).

#### IV. TRANSPORT

DFT as presented in the previous sections is a ground-state theory. However, generalizations are available which allow

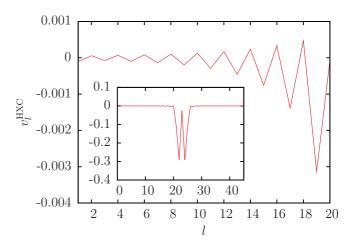


FIG. 6. (Color online) Hartree-exchange-correlation potential  $v_l^{\rm HXC}$  in OEP for a long chain with m=20 noninteracting sites attached on each side of the five-site quantum dot with parameters  $v_{\rm gate}/t=0.5$  and V/t=0.5. In the figure,  $v_l^{\rm HXC}$  is shown for the noninteracting sites  $l=1,\ldots,m$  and for the whole chain in the inset.

one to calculate densities at finite temperature and under nonequilibrium conditions <sup>18</sup> and thus—via the continuity equation—the current through the quantum dot. The goal of this section is to calculate the dc conductance of the quantum dot when a small voltage difference is applied. We extract the dc conductance from a calculation of the dynamic density response function, and the connection to the standard Meir-Wingreen formula <sup>19</sup> is made.

### A. Conductance from density response

We start with the current flowing from the left reservoir into the dot, which is given by the time derivative of the particle number in the reservoir,

$$I = e\dot{N}_L = e\sum_k \dot{n}_{kL},\tag{22}$$

i.e.,  $I(\omega) = -ie\omega N_L(\omega)$ , where -e is the electron charge. The frequency-dependent variation in the particle number  $N_L(\omega)$  appears as a response to a perturbation in the Kohn-Sham Hamiltonian of the form

$$\delta \hat{H}^s = \sum_{\alpha} \hat{n}_{\alpha} \delta v_{\alpha}^s, \tag{23}$$

where  $\delta v_{\alpha}^{s} = \delta v_{\alpha}^{\rm ext} + \delta v_{\alpha}^{\rm HXC}$  is the sum of an external potential and the induced Hartree-exchange-correlation potential. The summation  $\alpha$  includes both reservoirs,  $\alpha = kL, kR$ , and chain degrees of freedom,  $\alpha = l$ . The variation of the density at site  $\beta$  is then

$$\delta n_{\beta}(\omega) = -i \sum_{\alpha} \int \frac{d\epsilon}{2\pi} \mathcal{G}_{\epsilon+\omega}(\beta,\alpha) \delta v_{\alpha}^{s}(\omega) \mathcal{G}_{\epsilon}(\alpha,\beta), \quad (24)$$

where  $\mathcal{G}_{\epsilon}(\alpha,\beta)$  is the (zero temperature) Green's function of the single-particle Hamiltonian. It is useful to distinguish the Green's function of the reservoirs from the Green's function of the chain, and in the following we use the symbols  $g_{\epsilon}(kL)$  and  $g_{\epsilon}(kR)$  for the reservoir Green's functions and  $G_{\epsilon}(l,l')$  for a chain Green's function. The latter is given by

$$G_{\epsilon}(l,l') = G_{\epsilon}^{0}(l,l') + \sum_{m} G_{\epsilon}^{0}(l,m) \Sigma_{\epsilon}(m) G_{\epsilon}(m,l'), \quad (25)$$

where  $G_{\epsilon}^0(l,l')$  is the bare Green's function, i.e., the one for  $t_k=0$ , and the self-energy  $\Sigma_{\epsilon}(m)$  appears due to the coupling to the reservoirs. For our model Hamiltonian  $\Sigma_{\epsilon}(m)$  is nonzero only on the first and last site of the chain, m=1,N. The explicit expression for the first site is

$$\Sigma_{\epsilon}(1) = \sum_{k} |t_k|^2 g_{\epsilon}^0(kL), \tag{26}$$

where

$$g_{\epsilon}^{0}(kL) = \frac{1}{\epsilon - \epsilon_{k} + i\delta \operatorname{sgn}(\epsilon - \mu)}, \quad \delta = 0^{+},$$
 (27)

is the bare Green's function of state k in the left lead. For energies close to the chemical potential and for our special choice of the couplings  $t_k$  the self-energy then assumes the value  $\Sigma_{\epsilon}(1) = -it \operatorname{sgn}(\epsilon - \mu)$ . The Green's function for the states in the left reservoir finally is

$$g_{\epsilon}(kL) = g_{\epsilon}^{0}(kL) + g_{\epsilon}^{0}(kL) t_{k} G_{\epsilon}(1,1) t_{k} g_{\epsilon}^{0}(kL).$$
 (28)

A similar equation holds for the Green's function in the right reservoir.

The variation of the particle number in the reservoirs can be represented graphically as

where the full line denotes a reservoir Green's function,  $g_{\epsilon}^0(kL)$  or  $g_{\epsilon}^0(kR)$ , the broken line is the chain Green's function  $G_{\epsilon}(l,l')$ , the cross corresponds to a hopping process between reservoir and chain, and the two dots in each diagram are density vertices. In order to calculate the dc conductance of the system we have to evaluate these diagrams for small but finite frequency, and we have to identify contributions that diverge as  $1/\omega$  as  $\omega$  goes to zero. Such divergences are found in diagrams (c), (d), and (e). In all three cases the diverging contribution arises from the region in the  $\epsilon$  integration where  $\epsilon < \mu < \epsilon + \omega$ . For diagram (c), for instance, the relevant contribution is

$$\delta N_L^{(c)} = -i \int_{\mu-\omega}^{\mu} \frac{d\epsilon}{2\pi} G_{\epsilon+\omega}(1,1) \sum_k t_k^2 \left(\frac{1}{\epsilon+\omega-\epsilon_k+i\delta}\right)^2 \times \frac{1}{\epsilon-\epsilon_k-i\delta} \delta v_{kL}^s. \tag{30}$$

In the next step the k summation in the second line is replaced by an integral. Clearly the dominant contribution to the k integration comes from a small region around the Fermi energy. Assuming that neither the potential  $\delta v_{kL}^s$  nor the coupling  $t_k$  are singular around the Fermi momentum, we find  $\sum_k (\cdots) = i \Gamma_L \delta v_{kL}^s / \omega^2$ , where the potential has to be evaluated at the Fermi energy. The variation of the particle number in the left reservoir hence is

$$\delta N_L^{(c)} = \frac{\delta v_{kL}^s}{2\pi\omega} \Gamma_L G_\mu^R(1,1). \tag{31}$$

The retarded chain Green's function at the chemical potential,  $G_{\mu}^{R}(1,1)$ , appears since  $\epsilon + \omega > \mu$  in Eq. (30), and we consider the limit  $\omega \to 0$ .

Using similar arguments for the diagrams (d) and (e), we find

$$\delta N_{L}^{(d)} = -\frac{\delta v_{kL}^{s}}{2\pi\omega} \Gamma_{L} G_{\mu}^{A}(1,1), \qquad (32)$$

$$\delta N_{L}^{(e)} = \frac{i\delta v_{kL}^{s}}{2\pi\omega} \left[ \Gamma_{L} G_{\mu}^{R}(1,1) \Gamma_{L} G_{\mu}^{A}(1,1) \right] + \frac{i\delta v_{kR}^{s}}{2\pi\omega} \left[ \Gamma_{L} G_{\mu}^{R}(1,N) \Gamma_{R} G_{\mu}^{A}(N,1) \right]. \qquad (33)$$

Using finally the relation

$$G_{\mu}^{R}(1,1) - G_{\mu}^{A}(1,1)$$

$$= -iG_{\mu}^{R}(1,1)\Gamma_{L}G_{\mu}^{A}(1,1) - iG_{\mu}^{R}(1,N)\Gamma_{R}G_{\mu}^{A}(N,1), \quad (34)$$

the complete singular contribution to the density in the reservoir reads

$$\delta N_L = \left(\delta v_{kR}^s - \delta v_{kL}^s\right) \frac{i}{2\pi\omega} \Gamma_L G_\mu^R(1, N) \Gamma_R G_\mu^A(N, 1). \tag{35}$$

This enables us to write the current as the product of a conductance  $G_{KS}$  and a voltage  $U_{KS}$ ,

$$I = -ie\omega \delta N_L = G_{KS} U_{KS}, \tag{36}$$

where the expression for the conductance agrees with the standard Meir-Wingreen formula for noninteracting electrons,

$$G_{KS} = \frac{e^2}{2\pi\hbar} \Gamma_L G_{\mu}^R(1, L) \Gamma_R G_{\mu}^A(L, 1), \tag{37}$$

and the voltage in the Kohn-Sham system is the sum of the applied voltage and an exchange-correlation contribution,  $U_{\rm KS}=U+U^{\rm xc}$ , with

$$eU = \delta v_{kR}^{\text{ext}} - \delta v_{kL}^{\text{ext}}, \quad eU^{\text{xc}} = \delta v_{kR}^{\text{HXC}} - \delta v_{kL}^{\text{HXC}}.$$
 (38)

Here, as well as in Eqs. (31)–(35) k has to be replaced by its value at the Fermi energy.

Notice that only the exchange-correlation potentials in the reservoirs but not in the chain contribute to the total voltage. Our result is thus consistent with that of Ref. 15, where it has been shown that the exact current can be expressed in terms of a Landauer-type formula<sup>20</sup> in which the electrochemical potential of the leads is shifted by the voltage-induced variation of the exchange-correlation potential, and with the statements of Refs. 14 and 21 that static DFT gives the exact linear-response conductance provided that the dynamic exchange-correlation potential vanishes deep inside the leads.

We remark that  $U^{\rm xc}$  is a purely dynamic effect that cannot be captured by any adiabatic approximation. However,  $U^{\rm xc}$  can be assessed via reverse engineering: If we know the exact static densities and the exact conductance, then the ratio of the exact conductance and the Kohn-Sham conductance, Eq. (37), is equal to the ratio of the total and the external voltage,  $G/G_{\rm KS}=U_{\rm KS}/U$ .

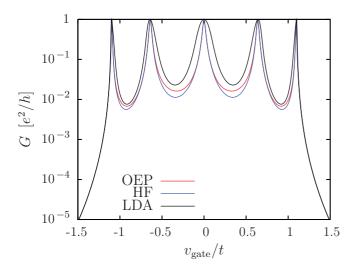


FIG. 7. (Color online) Conductance G as a function of  $v_{\rm gate}$  for V/t=0.25. The OEP and LDA curves refer to Kohn-Sham conductances that are obtained within static density functional theory as explained in the text. HF corresponds to a self-consistent Hartree-Fock calculation.

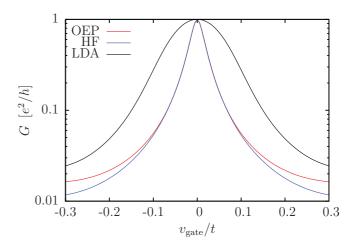


FIG. 8. (Color online) Conductance G as a function of  $v_{\rm gate}$  close to the central peak for V/t=0.25.

#### B. Results

Figure 7 shows the conductance as a function of the gate voltage in the case of a weak interaction, V=0.25t. One observes five resonances at the gate voltages where the particle number on the dot changes (compare with Fig. 2). The LDA overestimates the width of the resonances just as it overestimates the width of the steps in the particle number. We also include OEP and Hartree-Fock (HF) results in the figure. For weak interaction both methods predict identical charge densities; for the present interaction strength the difference in particle number on the dot is less than  $7 \times 10^{-3}$ . The conductances are also close to each other.

In Fig. 8 we show the region close to zero gate voltage in more detail. Near the resonance the HF and OEP results are almost indistinguishable; however, far from the resonance a significantly different conductance is found. This difference is due to the exchange-correlation contribution to the voltage,  $U^{\rm xc}$ . To substantiate this point we analyze the correction to the

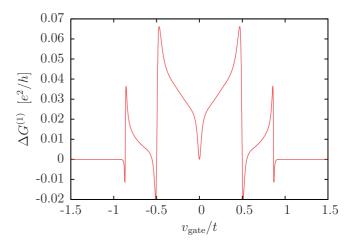


FIG. 9. (Color online) Linear contribution  $G^{(1)}$  of the expansion of the conductance  $G=G^{(0)}+G^{(1)}V/t+G^{(2)}(V/t)^2+\cdots$  in powers of the interaction strength. The difference between the OEP result and the HF conductance,  $\Delta G^{(1)}=G^{(1)}_{\rm OEP}-G^{(1)}_{\rm HF}$ , is plotted as a function of  $v_{\rm gate}$ .

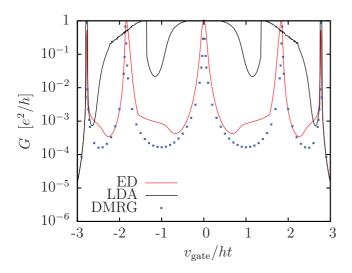


FIG. 10. (Color online) Conductance G as a function of  $v_{\text{gate}}$  for V/t = 2; ED corresponds to the Kohn-Sham conductance obtained from the diagonalization of small clusters, the DMRG data are taken from Ref. 13.

conductance to first order in the interaction strength V; in this case HF yields correct results.

As demonstrated in Fig. 9 the conductances obtained by the OEP and HF approaches differ considerably—although the densities are identical. Figure 9 has been obtained for a chain length N=9, but we have checked that even for much longer chains (up to N=25) there is no visible change in the results. This means that  $U^{\rm xc}$  remains nonzero even far from the interacting region.

Figure 10 shows the conductance for the relatively strong interaction strength V=2t, comparing the LDA, the ED method, and the numerically exact conductance obtained with the DMRG in Ref. 13. Although the positions of the resonances are reasonable, the LDA predicts conductances that differ by several orders of magnitude from the exact ones. The ED results are considerably better. In particular, near the resonances the ED method predicts conductances that are close to the DMRG values.

#### V. SUMMARY AND CONCLUSIONS

We studied the ground-state density profile and the conductance of a model quantum dot comparing DFT and exact results. The electron density in the ground state can be obtained reliably using nonlocal exchange-correlation potentials. While for weak interaction the OEP approach gives good results, in the case of intermediate or strong interaction strengths a nonlocal potential extracted from the exact diagonalization of small clusters (DFT + ED) works well. Although we have so far applied the DFT + ED method only to a system with a small interacting region we speculate that a generalization to models with interaction on all lattice sites is possible.

For the conductance our results are not so clear-cut. In our simple model there exist five well-separated resonances in the conductance, G, as a function of the gate voltage. The Kohn-Sham conductance,  $G_{\rm KS}$ , reproduces very well the position and the width of these resonances, whereas in the valleys between the conductance peaks we find pronounced deviations. This behavior has been discussed qualitatively in Refs. 14 and 22 involving the Friedel sum rule.

As the origin of the discrepancies between G and  $G_{\rm KS}$  we have identified an exchange-correlation correction to the voltage in the Kohn-Sham system,  $U^{\rm xc}=U_{\rm KS}-U$ , and  $G/G_{\rm KS}=U_{\rm KS}/U$ , compare the discussion in relation with Eq. (38). The correction  $U^{\rm xc}$  is a dynamical exchange-correlation potential in the reservoirs that cannot be obtained within a static calculation. We found no significant difference between  $U^{\rm xc}$  for small chains with N=9 sites and long chains up to N=25 sites suggesting that  $U^{\rm xc}$  remains finite for chains of infinite length. We believe that this finding is related to "ultra-nonlocality," which is an inherent problem in time-dependent density functional theory.  $^{23,24}$ 

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